INTEGRATED CIRCUITS

DATA SHEET



74LV241Octal buffer/line driver (3-State)

Product specification Supersedes data of 1997 Feb 19 IC24 Data Handbook





Octal buffer/line driver (3-State)

74LV241

FEATURES

- Optimized for low voltage applications: 1.0 to 3.6 V
- ullet Accepts TTL input levels between V_{CC} = 2.7 V and V_{CC} = 3.6 V
- \bullet Typical V_{OLP} (output ground bounce) < 0.8 V at V_{CC} = 3.3 V, T_{amb} = 25°C
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at V_{CC} = 3.3 V, T_{amb} = 25°C
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV241 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT241.

The 74LV241 is an octal non-inverting buffer/line driver with 3-State outputs. The 3-State outputs are controlled by the output enable inputs $1\overline{\text{OE}}$ and 2OE.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay 1A _n to 1Y _n ; 2A _n to 2Y _n	C _L = 15 pF; V _{CC} = 3.3 V	8.0	ns
C _I	Input capacitance	7 3°	3.5	pF
C _{PD}	Power dissipation capacitance per buffer	$V_{CC} = 3.3 \text{ V}$ $V_{I} = \text{GND to } V_{CC}^{1}$	30	pF

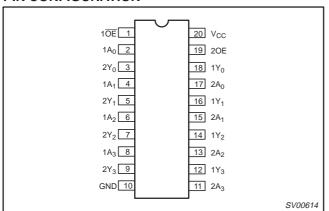
NOTE

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW) $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; C_L = output load capacitance in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

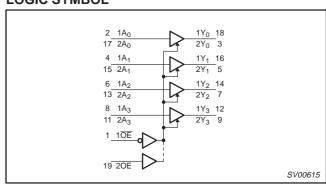
ORDERING INFORMATION

				_
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic DIL	-40°C to +125°C	74LV241 N	74LV241 N	SOT146-1
20-Pin Plastic SO	-40°C to +125°C	74LV241 D	74LV241 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +125°C	74LV241 DB	74LV241 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV241 PW	74LV241PW DH	SOT360-1

PIN CONFIGURATION



LOGIC SYMBOL



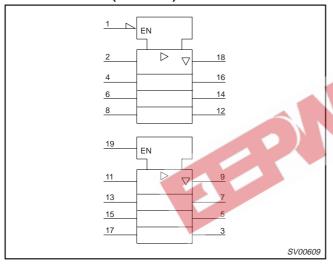
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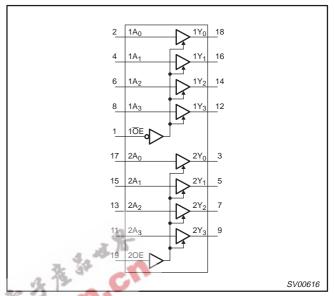
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	1 OE	Output enable input (active LOW)
2, 4, 6, 8	1A ₀ to 1A ₃	Data inputs
3, 5, 7, 9	2Y ₀ to 2Y ₃	Bus outputs
10	GND	Ground (0 V)
17, 15, 13, 11	2A ₀ to 2A ₃	Data inputs
18, 16, 14, 12	1Y ₀ to 1Y ₃	Bus outputs
19	20E	Output enable input (active HIGH)
20	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



FUNCTIONAL DIAGRAM



FUNCTION TABLE

		INP	JTS		OUTPUT			
	1OE	1A _n	20E	2A _n	1Y _n	2Y _n		
	L	L	Н	L	Н	L		
Γ	L	Н	Н	Н	L	Н		
	Н	Х	L	Х	Z	Z		

HIGH voltage level LOW voltage level don't care

high impedance OFF-state

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	3.6	V
V _I	Input voltage		0	_	V _{CC}	V
Vo	Output voltage		0	_	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.0V to 2.0V V _{CC} = 2.0V to 2.7V V _{CC} = 2.7V to 3.6V	- - -	- - -	500 200 100	ns/V

NOTE:

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage	36 3	-0.5 to +4.6	V
±I _{IK}	DC input diode current	$V_{I} < -0.5$ or $V_{I} > V_{CC} + 0.5V$	20	mA
±Ιοκ	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
±ΙΟ	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with –bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{tot}	Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

^{1.} The LV is guaranteed to function down to $V_{CC} = 1.0V$ (input levels GND or V_{CC}); DC characteristics are guaranteed from $V_{CC} = 1.2V$ to $V_{CC} = 3.6V$.

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-40)°C to +8	5°C	-40°C to	+125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2V	0.9			0.9		
V_{IH}	HIGH level Input voltage	V _{CC} = 2.0V	1.4			1.4		V
	Tonago	V _{CC} = 2.7 to 3.6V	2.0			2.0		1
		V _{CC} = 1.2V			0.3		0.3	
V_{IL}	LOW level Input voltage	V _{CC} = 2.0V			0.6		0.6	V
	Tonago	V _{CC} = 2.7 to 3.6V			0.8		0.8	1
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$		1.2				
V	HIGH level output	$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	1.8	2.0		1.8] ,
V _{OH}	voltage; all outputs	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 100\mu A$	2.5	2.7		2.5		1 '
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.8	3.0	5-	2.8		1
V _{OH}	HIGH level output voltage; BUS driver outputs	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 8mA$	2.40	2.82	n	2.20		V
		$V_{CC} = 1.2V$; $V_I = V_{IH}$ or V_{IL} , $I_O = 100 \mu A$. 1	0				
V	LOW level output	$V_{CC} = 2.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100\mu A$	60	0	0.2		0.2	
V_{OL}	voltage; all outputs	$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 100\mu A$		0	0.2		0.2]
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	
V _{OL}	LOW level output voltage; BUS driver outputs	V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = 8mA		0.20	0.40		0.50	V
I _I	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
l _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V$; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND			5		10	μА
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μА
ΔI_{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$			500		850	μА

NOTE

^{1.} All typical values are measured at T_{amb} = 25°C.

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AC CHARACTERISTICS

GND = 0V; $t_r = t_f \le 2.5 ns$; $C_L = 50 pF$; $R_L = 1 K\Omega$

			CONDITION			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	CONDITION		40 to +85 °	С	-40 to -	⊦125 °C	UNIT	
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX		
			1.2		45					
. .	Propagation delay 1A _n to 1Y _n ;	Figures 4	2.0		15	31		36		
t _{PHL} /t _{PLH}	$2A_n$ to $2Y_n$	Figures 1	2.7		11	23		26	ns	
			3.0 to 3.6		9 ²	18		21		
			1.2		55					
l	3-State output enable time 1 OE to 1Y _n ;	F: 0.0	Figure 2 0 0	2.0		19	36		44	
t _{PZH} /t _{PZL}	20E to 2Y _n	Figures 2, 3	2.7		14	26		33	ns	
			3.0 to 3.6		10 ²	21		26		
			1.2		60					
	3-State output disable time	F: 0 0	2.0		22	39		48		
^l PHZ/ ^l PLZ	t _{PHZ} /t _{PLZ} 1 OE to 1Y _n ; 2OE to 2Y _n	Figures 2, 3	2.7	9- <u> </u>	17	29		36	ns	
			3.0 to 3.6	107	13 ²	24		29		

NOTES:

- 1. Unless otherwise stated, all typical values are measured at T_{amb} = 25°C
- 2. Typical values are measured at $V_{CC} = 3.3 \text{ V}$.

AC WAVEFORMS

 $\begin{array}{l} V_{M} = 1.5 \; \text{V at V}_{CC} \geq 2.7 \; \text{V; V}_{M} = 0.5 \; \text{V} \times \text{V}_{CC} \; \text{at V}_{CC} < 2.7 \; \text{V} \\ V_{X} = V_{OL} + 0.3 \; \text{V at V}_{CC} \geq 2.7 \; \text{V; V}_{X} = V_{OL} + 0.1 \; \text{V} \times \text{V}_{CC} \; \text{at V}_{CC} < 2.7 \; \text{V} \\ V_{Y} = V_{OH} - 0.3 \; \text{V at V}_{CC} \geq 2.7 \; \text{V; V}_{Y} = V_{OH} - 0.1 \times \text{V}_{CC} \; \text{at V}_{CC} < 2.7 \; \text{V} \\ \end{array}$

 $V_{\mbox{\scriptsize OL}}$ and $V_{\mbox{\scriptsize OH}}$ are the typical output voltage drop that occur with the output load.

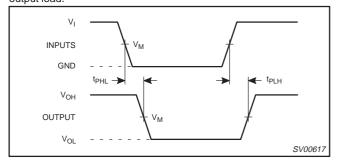


Figure 1. Input $(1A_n, 2A_n)$ to output $(1Y_n, 2Y_n)$ propagation delays.

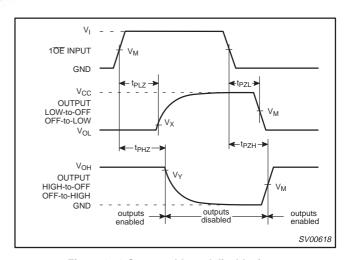


Figure 2. 3-State enable and disable times.

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AC WAVEFORMS (Continued)

 V_M = 1.5 V at V_{CC} \geq 2.7 V; V_M = 0.5 V \times V $_{CC}$ at V $_{CC}$ < 2.7 V $_{VX}$ = V $_{OL}$ + 0.3 V at V $_{CC}$ \geq 2.7 V; V $_{X}$ = V $_{OL}$ + 0.1 V \times V $_{CC}$ at V $_{CC}$ < 2.7 V

 V_Y = V_{OH} - 0.3 V at V_{CC} \geq 2.7V; V_Y = V_{OH} - 0.1 \times V_{CC} at V_{CC} < 2.7

 $V_{\mbox{\scriptsize OL}}$ and $V_{\mbox{\scriptsize OH}}$ are the typical output voltage drop that occur with the output load.

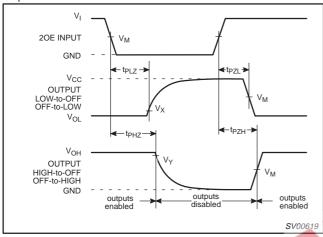


Figure 3. 3-State enable and disable times for input 20E.

TEST CIRCUIT

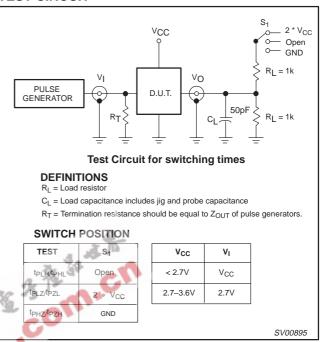


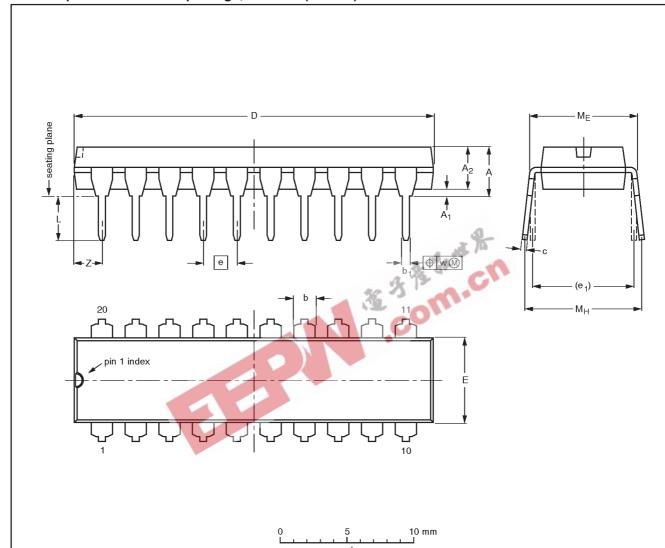
Figure 4. Load circuitry for switching times.

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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

D1101E11010	`														
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

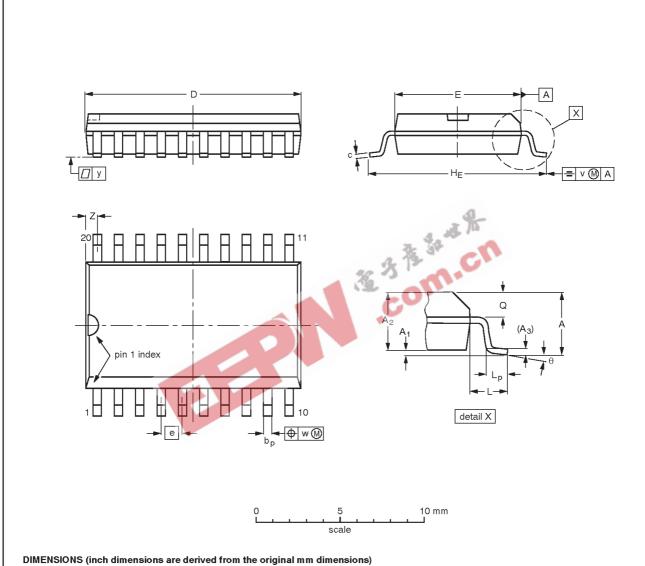
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE	
SOT146-1			SC603			-92-11-17 95-05-24	

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

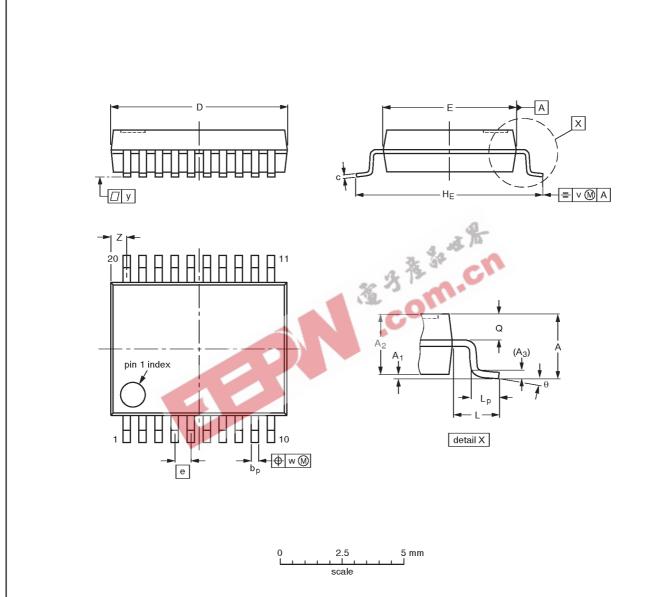
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION		
SOT163-1	075E04	MS-013AC			-92-11-17 95-01-24	

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

						-,												
UNIT	A max.	Α1	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

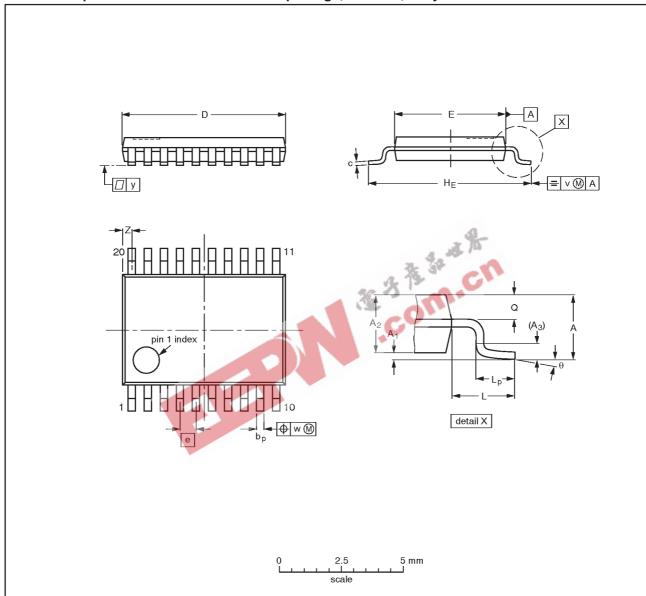
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT339-1		MO-150AE				-93-09-08 95-02-04	

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE
SOT360-1		MO-153AC				-93-06-16 95-02-04

Octal buffer/line driver (3-State)

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Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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